Models

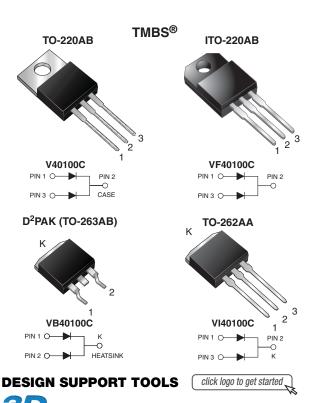
V40100C-E3, VF40100C-E3, VB40100C-E3, VI40100C-E3

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Dual High Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low $V_F = 0.38 \text{ V}$ at $I_F = 5 \text{ A}$



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 20 A					
V_{RRM}	100 V					
I _{FSM}	250 A					
V_F at $I_F = 20$ A	0.61 V					
T _J max.	150 °C					
Package	TO-220AB, ITO-220AB, D ² PAK (TO-263AB), TO-262AA					
Circuit configuration	Common cathode					

FEATURES





- · Low forward voltage drop, low power losses
- High efficiency operation

- (e3)
- Meets MSL level 1, per J-STD-020, RoHS LF maximum peak of 245 °C (for TO-263AB compliant package)
- · Low thermal resistance
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB, ITO-220AB, and TO-262AA package)
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, D^2PAK (TO-263AB), and TO-262AA

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)								
PARAMETER		SYMBOL	V40100C	VF40100C	VB40100C	VI40100C	UNIT	
Maximum repetitive peak reverse voltage		V _{RRM} 100			00		V	
per	per device		40				Α	
Maximum average forward rectified current (fig. 1) per		I _{F(AV)}	20					
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	250			Α		
Non-repetitive avalanche energy at T _J = 25 °C, L = 90 mH per diode		E _{AS}	230				mJ	
Peak repetitive reverse current at t_p = 2 μ s, 1 kHz, T_J = 38 °C \pm 2 °C per diode		I _{RRM}	1.0			А		
Voltage rate of change (rated V _R)		dV/dt	10 000			V/µs		
Operating junction and storage temperature range		T _J , T _{STG}	-40 to +150			°C		

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Breakdown voltage ⁽²⁾	I _R = 1.0 mA	T _A = 25 °C	V_{BR}	100 (minimum)	1	V	
	I _R = 10 mA			105 (minimum)	-		
Instantaneous forward voltage per diode (1)	I _F = 5 A	T _A = 25 °C T _A = 125 °C	V _F	0.47	-	V	
	I _F = 10 A			0.54	ı		
	I _F = 20 A			0.67	0.73		
	I _F = 5 A			0.38	-		
	I _F = 10 A			0.45	-		
	I _F = 20 A			0.61	0.67		
Reverse current at rated V _R per diode ⁽²⁾	V _R = 70 V	T _A = 25 °C	I _R	9	-	μΑ	
		T _A = 125 °C		10	ı	mA	
	V _B = 100 V	T _A = 25 °C		-	1000	μΑ	
	VH = 100 V	T _A = 125 °C		21	45	mA	

Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER SYMBOL V40100C VF40100C VB40100C VI40100C UNIT							
Typical thermal resistance per diode	$R_{\theta JC}$	2.0	4.0	2.0	2.0	°C/W	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	V40100C-E3/4W	1.85	4W	50/tube	Tube			
ITO-220AB	VF40100C-E3/4W	1.75	4W	50/tube	Tube			
TO-263AB	VB40100C-E3/4W	1.39	4W	50/tube	Tube			
TO-263AB	VB40100C-E3/8W	1.39	8W	800/tube	Tape and reel			
TO-262AA	VI40100C-E3/4W	1.46	4W	50/tube	Tube			

RATINGS AND CHARACTERISTICS CURVES ($T_A = 25$ °C unless otherwise noted)

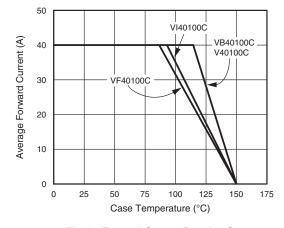


Fig. 1 - Forward Current Derating Curve

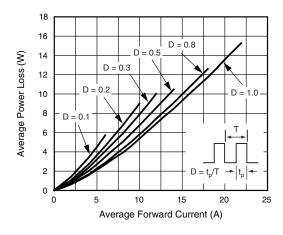


Fig. 2 - Forward Power Loss Characteristics Per Diode

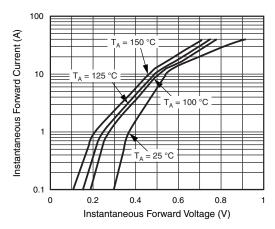


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

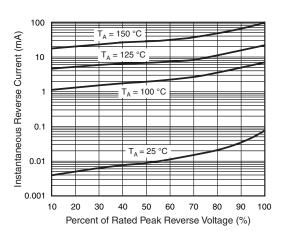


Fig. 4 - Typical Reverse Characteristics Per Diode

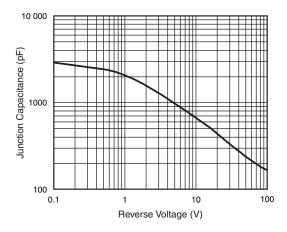


Fig. 5 - Typical Junction Capacitance Per Diode

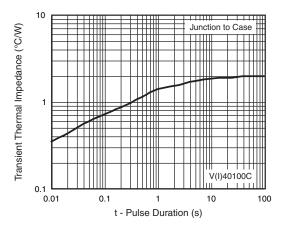


Fig. 6 - Typical Transient Thermal Impedance Per Diode

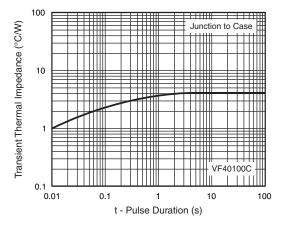
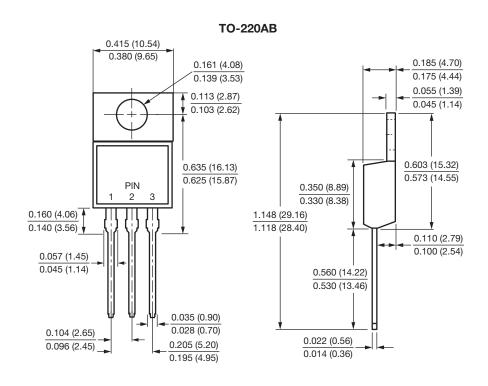


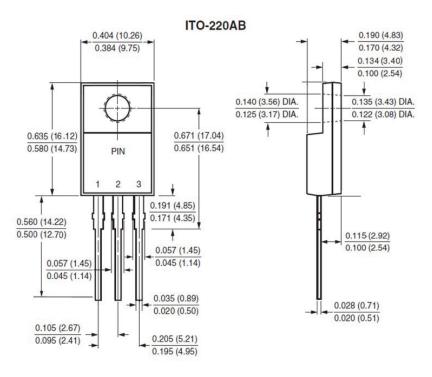
Fig. 7 - Typical Transient Thermal Impedance Per Diode

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

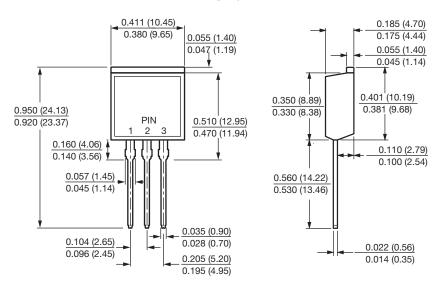




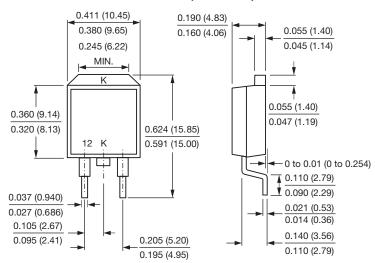
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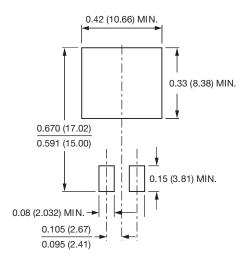
TO-262AA



D²PAK (TO-263AB)



Mounting Pad Layout





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